

23 **1. Introduction**

24 Titanium alloys are widely used in demanding engineering applications due to their
25 high specific strength, corrosion resistance and excellent fatigue limit strength-to-weight
26 ratio [1]. They have been central to the development of jet engines and airframes for the
27 aerospace industry, emerging as the chosen materials for safety-critical components such as
28 blades and disks, as well as airframe components subject to complex loads such as wing
29 boxes and landing gear [1–3]. Hydrogen embrittlement (HE) has been an important concern
30 especially in the power generation, pipeline and aerospace industries, causing catastrophic
31 failures of high-strength components [4,5]. Due to their extensive use in engineering
32 applications involving hydrogen, steels have received by far the most research attention of
33 any material in this field. In contrast, prior to the 1950s, titanium was widely considered to
34 be insusceptible to HE in aqueous environments due to its protective oxide film [2]. However,
35 from the 1960s onward evidence accumulated that hydrogen leads to a range of degradation
36 phenomena in titanium, which continues to cause engineering concerns for industry [2,6–
37 10]. The majority of research in the hydrogen embrittlement (HE) of titanium focuses on the
38 behavior of hydrogen once it is absorbed into the metal [2,8,11]. In this work we focus on the
39 initial adsorption/absorption processes at the surface [12,13].

40 The surface state is a critical engineering variable controlling the absorption of H
41 into a metal. For example, the effectiveness of surface oxide layers in limiting H-absorption
42 led to the exploration of H-permeation barrier coatings for the prevention against HE in
43 steels [14,15]. The presence of surface deformation or roughness can also influence H-uptake.
44 For example, the effect of plastic deformation on electrochemical activity has been
45 investigated for various metals in the context of corrosion [16–21] or in the field of
46 electrochemical catalysts [22–25]. Electrons around a peak escape easier than those in a
47 valley, thus, surface roughness increases local fluctuation of the electron work function,
48 which leads to accelerated corrosion on a rough surface [16]. Plastic deformation, which
49 generates an increase in surface roughness, residual stress as well as dislocation density,
50 generally promotes the corrosion of metals, as reported for the case of copper [16,21],
51 pipeline steel [20] and Ti-6Al-4V [17,19]. In plastically-deformed Ti-6Al-4V, both surface
52 roughness and near-surface dislocation density influence the corrosion behavior. The

53 development of surface roughness plays a predominant role in the higher corrosion current
54 density [19]. The rise in dislocation density, on the other hand, can also increase the
55 passivation current density by multiplying the number of active dissolution sites in the
56 passivation film [17]. These effects create significant engineering concerns, yet, decoupling
57 their role can be challenging since they can be introduced (at varying levels) even by the
58 application of a single surface treatment. Moreover, there are interesting opportunities that
59 arise. For example, as will be shown in Figure 1, intriguing HE-resistance behavior can be
60 realized even by simply cutting Ti-6Al-4V specimens. This is especially interesting since cut
61 edges are typically detrimental to mechanical properties (e.g. cause reduction in formability
62 of sheet metals) [26–28]. An improved understanding of this mechanical response also
63 requires physical insights regarding the underlying microstructural processes.

64 With these motivations, here we examine hydrogen effects in Ti-6Al-4V. To this end,
65 systematic electrochemical charging experiments and mechanical tests were performed,
66 varying only the surface characteristics between tests. Clear distinctions between specimens
67 with different roughness were observed upon electrochemical H-charging, both in the
68 microstructure and in the resulting mechanical response during tensile tests. In order to
69 better understand the H-transport process through the surfaces with different finishes, we
70 carried out a quantitative microscopic analysis of hydrogen recombination, thermal
71 desorption spectroscopy (TDS) and time-of-flight secondary ion mass spectroscopy (ToF-
72 SIMS) measurements, and discussed these results in connection with the surface
73 microstructure maps obtained.

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75 **2. Experimental methodology**

76 **2.1. Specimen preparation and tensile tests**

77 A commercial Ti-6Al-4V alloy with a bimodal microstructure containing lamellar and
78 equiaxed regions was used in this study. The alloy met the ASTM B265 specification [29]
79 (initial H concentration < 15 wppm). The microstructure is typical of aeroengine Ti-6Al-4V
80 disk product, with primary α grains ($\sim 20 \mu\text{m}$ in size) and transformed β regions composed

81 of secondary α lamellae separated by continuous β phase. A backscattered electron (BSE)
82 micrograph of the starting material is shown in Figure 1(a), where the α phase appears dark,
83 and the β phase appears bright. An electron backscattered diffraction (EBSD) inverse pole
84 figure map of the same region is shown in Figure 1(b) which indicates a reasonably weak α
85 texture with no evidence of macrozones. The secondary α lamellae occur in colonies of
86 similar orientation and therefore can often appear as single grains in such EBSD maps.

87 Room temperature electrochemical H-charging experiments were carried out using
88 an electrochemical charging setup described in a previous work [30]. Although the setup was
89 designed primarily for *in situ* use in a scanning electron microscope (SEM), it was used
90 outside of the SEM for this work. A plate specimen is fixed to the top of the device, sealing a
91 chamber which contains the electrolyte and a platinum counter electrode (Figure SI1 in
92 Supplementary Materials). In contrast to a normal electrochemical H-charging method that
93 immerses a whole specimen into a liquid electrolyte, the setup charges hydrogen only at one
94 flat side of a plate specimen, and the electrolyte is not in contact with any sharp edge of the
95 specimen. A sharp edge would have an influence on H-charging similar to the roughness
96 effect investigated in this work. By utilizing the setup, we could exclude the edge effect as
97 well as provide uniform hydrogen flux to the charging surface.

98 Ti-6Al-4V plates were H-charged using a solution of 5 vol.% sulfuric acid + 5g/L
99 ammonium thiocyanate in distilled water as the electrolyte. The setup ensures that only a
100 circular area of 14 mm diameter is charged, allowing the nominal current density to remain
101 constant for each specimen. A current density of 0.5 mA cm⁻² and a charging time of 40 h
102 were used for all specimens. Four different types of specimens were charged, and the only
103 alteration among the specimens was the preparation method used for the specimen charging
104 surface, which is summarized in Table 1. A larger number in the specimen name implies a
105 finer surface finish for its final preparation step. **A thickness-controllable specimen mount
106 was used for grinding and polishing the specimens (see Supplementary Materials for the
107 details), and the final thickness of the plate specimens was 300-400 μ m with an error of \pm 10
108 μ m within a single plate (measured using a digital micrometer).**

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110 **Table 1.** Details of the methods used to prepare the H-charging surface of each specimen. Whole preparation
111 steps of each specimen include the preparation steps of the one above it.

Specimen Name	Final preparation step	Details of final surface preparation step
S1	As-cut	Cut using wire electrical discharge machining (WEDM)
S2	Ground	Ground with 800 grit silicon carbide grinding papers (~12 μm particle size)
S3	Coarse-polished	Polished with 3 and 1 μm diamond suspensions in sequence
S4	Fine-polished	Polished with a mixture of a basic colloidal silica suspension (pH 9.8, ~50 nm particle size) and 30% hydrogen peroxide by a volume ratio of 85:15.

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113 Uniaxial tensile tests were performed to investigate the macroscopic HE. Tensile
114 coupons with gauge dimensions of 3 mm length and 1 mm width were machined from the
115 uncharged and H-charged specimens using wire electrical discharge machining (WEDM). A
116 maximum of four tensile specimens was extracted from a single H-charged plate, each with
117 the entire gauge section located inside the H-charged area. A Deben MTEST2000 micro-
118 mechanical testing system was used for conducting the tensile tests at a strain rate of 5×10^{-4}
119 s^{-1} . Digital image correlation (DIC) was used to measure the strain values using a sprayed
120 speckle micropattern on the specimen surface.

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122 **2.2. Surface and sub-surface characterization**

123 Prior to H-charging, optical analysis of the specimen surfaces was carried out using
124 a Zygo optical microscope fitted with a scanning interferometry detector for analyzing
125 surface topography. An area of $437.5 \mu\text{m} \times 437.5 \mu\text{m}$ was analyzed with 1000×1000 pixels
126 (data points) for each specimen. Waviness (macroroughness and inclination) was calculated
127 by interpolation of a 10×10 grid in the whole range of data points for each scan, and removed
128 from the raw data of surface topography. Surface topography images (Figure 4) and
129 quantified values (Table 3) were obtained from the waviness-corrected data.

130 The specimens were characterized prior to H-charging using a JEOL JEM-2100F
131 transmission electron microscope (TEM) at 200 kV to observe the microstructure

132 underneath charging surface. TEM foils were prepared by focused-ion beam (FIB) lift-out
133 with a Ga⁺ beam source at 30 kV in a dual beam FEI Helios Nanolab 600. A platinum
134 containing layer was initially deposited on the surface to minimize damage during ion
135 milling. The foils were thinned to become electron transparent with a thickness of ~150 nm.
136 TEM images were taken under scanning TEM (STEM) mode to obtain good microstructural
137 and dislocation contrast; complementary STEM-EDS was also performed (see
138 Supplementary Materials). Post-charging microstructural investigation was carried out
139 using a Tescan MIRA3 SEM equipped with an EDAX Hikari EBSD camera. All cross-section
140 specimens for SEM-EBSD were prepared by wet grinding with SiC paper down to 800 grit,
141 polishing with 9 μm diamond suspension, and final polishing with a neutralized colloidal
142 silica suspension (a mixture of a basic colloidal silica suspension (pH 9.8, ~50nm particle
143 size) and 30% hydrogen peroxide by a volume ratio of 85:15) to avoid hydride formation
144 during polishing.

146 **2.3. Hydrogen entry investigation**

147 We measured the amount of hydrogen molecules (H₂) formed by recombination of H
148 to H₂, using an electrochemical cell combined with an optical microscope (OM, Olympus BX-
149 41 metallographic microscope). The structure of the experimental setup is described in
150 Figure 7(a). The specimen was covered with a polytetrafluoroethylene (PTFE) tape with a
151 silicone-based adhesive, and only a small specimen area less than 1 × 1 mm² was exposed to
152 the electrolyte, as shown in the examples in Figure 7(b). A 6mm-tall acrylic cell body with a
153 cylindrical hole (diameter = 6.35 mm) was placed on the specimen, and the hole was filled
154 with the same electrolyte for H-charging. A Pt wire shaped into a ring was used as the counter
155 electrode and was placed at the top of the cell. A slide glass was used to cover the electrolyte
156 and to trap hydrogen bubbles inside the cell. OM images of the exposed specimen area with
157 hydrogen bubbles and the area below the slide glass were taken through the slide glass and
158 the electrolyte during H-charging with a current density of 2.5 mA cm⁻² (most of hydrogen
159 bubbles were trapped on the PTFE surface as shown in Figure 7(b), and few bubbles were
160 observed below the slide glass.).

161 Thermal desorption spectroscopy (TDS) was conducted for H-charged specimens,
162 using a SEM-TDS setup. A general-purpose residual gas analyzer unit (MKS e-Vision 2) and a
163 heating module (Kammrath-Weiss MZ.H12) were installed in the Tescan MIRA3 SEM. 0.3
164 mm-thick specimens with different surface finishing steps were pre-charged with H for 40 h
165 with the same electrochemical cell with the bubble OM analysis (diameter of the H-charged
166 area = 6.35 mm) before the TDS measurements. The residual gas analyzer measured the H_2
167 partial pressure (P_{H_2}) while the specimen was heated up to 900 °C with a heating rate of 10
168 K/min and cooled down to 50 °C by turning off the heater. The P_{H_2} curve during cooling was
169 used as the background signal curve and was subtracted from the heating curve.

170 Time of flight secondary-ion mass spectrometry (ToF-SIMS) was carried out on the
171 S2 and S4 specimens after H-charging to compare H content in the near-surface region. The
172 specimens were electroplated with a 20 μm -thick Ni layer prior to analysis, as this acts to
173 protect the specimen surface during ion milling and serves as a useful interface for reference
174 to the specimen surface. The Ni plating was conducted using a Watts bath solution of NiSO_4
175 (0.38 M), NiCl_2 (0.12 M), and H_3BO_3 (0.5 M) and a current density of 10 mA cm^{-2} . A focused
176 ion beam (FIB) of Xe^+ ions was used to mill ramps from the surface of the two specimens in
177 a Hiden Analytical Hi5 SIMS instrument, creating a surface that allows the secondary ion
178 signal to be analyzed with depth into the specimen. The ramps have an approximate size of
179 300 μm x 60 μm at an angle of 10 degrees into the specimen. The ramps were then analyzed
180 using Bi^+ ions with a separate SIMS instrument (IONTOF TOF.SIMS5-Qtac100 LEIS) coupled
181 with a ToF detector.

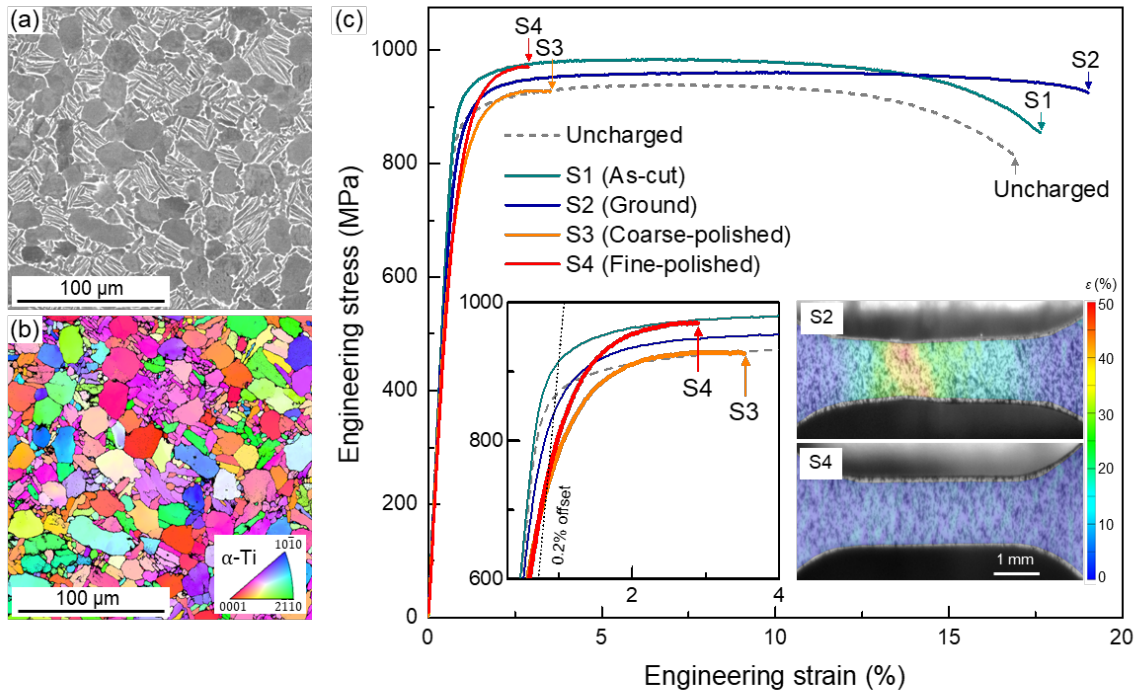
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183 3. Results

184 3.1. Effect of surface finish on HE behavior

185 The uniaxial tensile response for each of the H-charged specimens was investigated
186 to check the influence of H-charging. Figure 1(c) shows the stress-strain curves of the
187 different specimens after H-charging, and Table 2 summarizes the average properties based
188 on three repeats (error given by standard deviation). Interestingly, the H-charged specimens

189 of S1 and S2 exhibit similar tensile response to the uncharged S1 specimen, with a slight
 190 increase in fracture strain instead of the drastic reduction normally expected after H-
 191 charging [10,31]. In contrast, both polished specimens show premature fracture, with
 192 fracture strain reduced to 2.6% and 1.8% for the S3 and S4 specimens, respectively. The local
 193 strain maps captured at the moment before failure from DIC analysis (inset images in Figure
 194 1(c)) indicate a transition from ductile to brittle failure when comparing the S2 and S4
 195 specimens. The S2 specimen exhibits local strain over 40% at the point of failure and clear
 196 necking with strain bands visible at $\sim 45^\circ$, which is typical of ductile failure. For the S4
 197 specimen, the strain distribution is relatively uniform and fracture occurs without necking,
 198 which is characteristic of brittle failure. It is also observed that the average proof stress of
 199 the two polished specimens was ~ 100 MPa lower than the uncharged material. The decrease
 200 in yield strength is consistent with the literature [10,32,33], as hydride formation typically
 201 reduces the yield stress due to the generation of internal stresses from the volume expansion.



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 203 **Figure 1.** (a) BSE micrograph and (b) EBSD inverse pole figure map of Ti-6Al-4V alloy used in this study. (c)
 204 Tensile stress-strain curves of the uncharged specimen and H-charged specimens with four different surface
 205 states. The uncharged specimen was tested in the as-cut state. The inset graph shows an enlarged plot of stress-
 206 strain curves near fracture point of polished specimens. The inset images show the DIC maps of local Von Mises
 207 strain at the moment before failure for the ground (S2) and fine-polished (S4) specimens.

208 **Table 2.** Average mechanical properties of specimens obtained from three repeats for each case.

Specimen	0.2% proof stress (MPa)	UTS (MPa)	Fracture strain (%)
Uncharged	830 ± 20	912 ± 27	15.0 ± 1.2
S1	880 ± 19	963 ± 21	17.8 ± 1.2
S2	820 ± 15	952 ± 7	17.4 ± 2.2
S3	730 ± 8	912 ± 19	2.6 ± 0.2
S4	730 ± 40	961 ± 12	1.8 ± 0.4

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In the following analyses, we will focus our attention mostly on the difference in the failure strain between the non-polished (S1 and S2) and polished (S3 and S4) specimens. There are, however, as can be seen in Fig. 1 and Table 1, several other differences among the measured property values. To assess the significance of the differences, we carried out an error propagation analysis (See Supplementary Materials for the details). Miniaturizing test coupons make experiments more susceptible to influence from factors such as residual stresses, misalignment, and surface effects (particularly relevant here due to the different surface finishes used) [34]. **The uniformity of specimen thickness also influences observed stress values. Although the thickness deviation of 10 μm in a single specimen is fairly high precision for manual thickness control, it causes ~ 3 % error of stress values in a 350 μm-thick specimen. These factors create larger errors than those generated purely through measurement uncertainty, so it is not these experimental errors that the significance of the results will be measured against. In general, the variations in flow stress and UTS between specimens fall within the error range (the sum of the observed errors based on repeats and ~ 3 % error by the non-uniformity of thickness), so little attempt is made to compare these values among specimens.** However, the drastic decrease in fracture strain between polished and non-polished specimens is certainly significant, since the change is several times higher than the largest error reported. In the following sections, we focus on the origin of the different fracture strain in the H-charged specimens – in other words, the different susceptibility to hydrogen embrittlement by surface state.

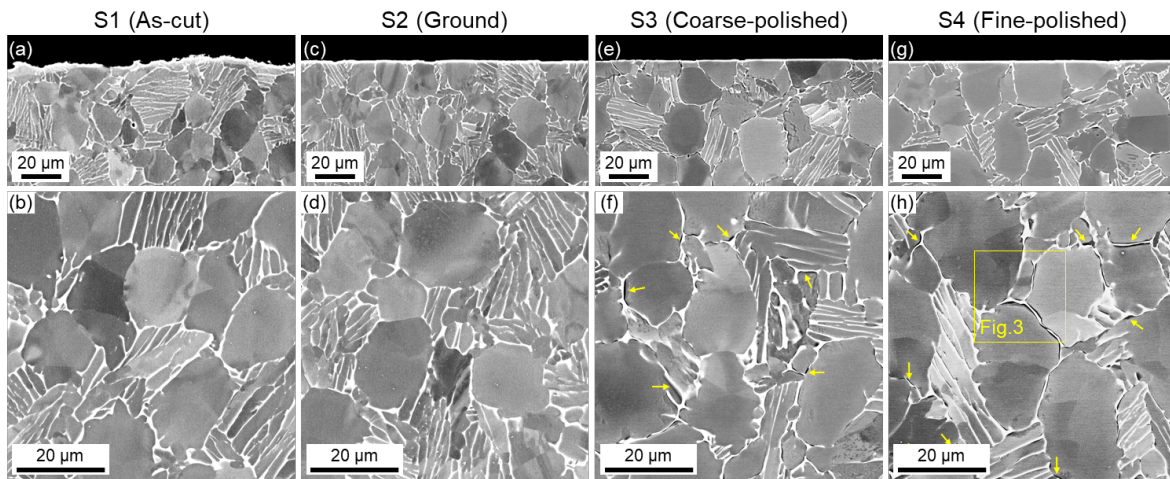
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Figure 2 presents the cross-section microstructures of H-charged specimens. Compared to the uncharged specimen in Figure 1(a), both polished specimens (S3 and S4) show new dark regions inside α grains as well as at the α/β phase boundary. The EBSD phase

233 map in Figure 3 indicates that the new dark phase is a hydride phase, which corresponds to
 234 a previous work [10]. Kim et al. and Chang et al. reported that the initial hydride phase in the
 235 Ti-6Al-4V alloy is formed at the α/β phase boundary (indicated by yellow arrows in Figure
 236 2(f,h)) and has a face-centered tetragonal crystal structure of stoichiometry close to $\text{TiH}_{1.5}$,
 237 as predicted by density functional theory calculation [10,35,36]. By further H-ingress,
 238 hydride laths would grow inside the primary α grains, similar to the hydrides that form in α -
 239 Ti alloys [31,37]. The hydride phase was observed throughout the entire thickness of the H-
 240 charged S3 and S4 plates. This is in contrast to, e.g. the electrochemical charging of single
 241 phase α -Zr alloys, where a hydride layer is formed that must then be interdiffused at elevated
 242 temperatures [38]. The solubility of H in α -Ti is low at room temperature, but is much higher
 243 in β -Ti [2], and so continuous β films can permit hydrogen permeation throughout the
 244 sample, as observed here. The formation of the soft-yet-brittle hydride phase is well known
 245 to result in severe embrittlement [10], as observed in Figure 1(c). Because the hydride forms
 246 at α/β phase interface throughout the sample, rather than just the formation of a hydride rim,
 247 this leads to embrittlement of the entire material. In contrast, even after H-charging for 40 h,
 248 both S1 and S2 specimens have a similar microstructure to the uncharged material, with no
 249 observed hydride formation (Figure 2(a-d)). This suggests that the absence of clear
 250 embrittlement in these two specimens originates from the reduced H-absorption, and the
 251 ground or as-cut surface finishes generate some kind of barrier to H entry and transport,
 252 which will be discussed further in the following sections.



253 **Figure 2.** Cross-section BSE images of the four specimens with different surface finishes, after H-charging for
 254 40 h. (a,b) S1, As-cut. (c,d) S2, Ground. (e,f) S3, Coarse-polished. (g,h) S4, Fine-polished. The upper row are
 255 images near the charging surfaces and the lower row are images near the center of the specimen.
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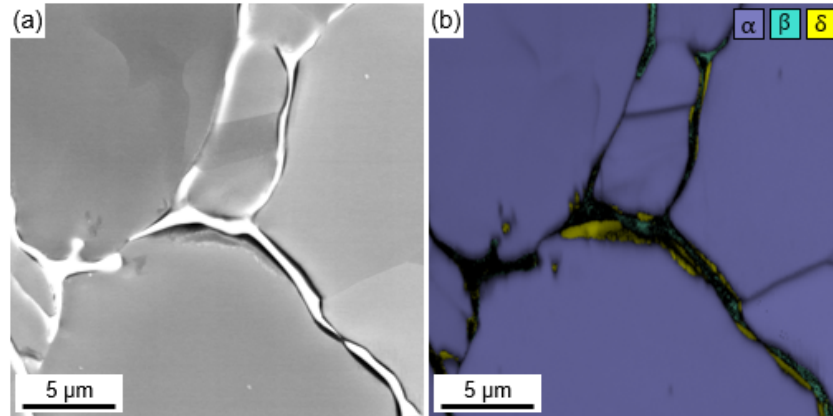


Figure 3. (a) BSE image and (b) EBSD phase map of the fine-polished (S4) specimen after H-charging for 40 h. Data points only with confidence index over 0.1 are shown here. Note that the hydride phase observed in the Ti-6Al-4V alloy has a slightly distorted structure ($c/a \sim 1.013$) compared to the equilibrium fcc δ -hydride phase found in pure Ti, and the β -phase is not well indexed (black) in the EBSD measurement due to non-uniform lattice expansion by H [10,39].

3.2. Surface roughness and subsurface deformation

Surface finish alters surface roughness and degree of deformation under the surface, both of which could influence H-entry and transport at the charging surface. Optical microscopy images of the four specimen surfaces before H-charging are shown in Figure 4(a-d). Both the non-polished surfaces (S1 and S2) exhibit sharp and protruding features, which are mainly re-solidified perturbations and plastically deformed clumps from grinding for the S1 specimen and S2 specimen, respectively. The S3 specimen has relatively shallow scratches but otherwise has a featureless surface, and the S4 surface is a mirror-like flat surface without any perceptible scratching.

For each area shown in Figure 4(a-d), surface topography maps were created by scanning interferometry, and the roughness and z-height distribution of each specimen was analyzed quantitatively based on the topography maps, which is shown in Figure 4(e-h). The clearly different levels of color contrast between the surface topography maps of the four specimens show the large dependence of surface fluctuation on surface finishing (note that the z-height scale in Figure 4(e) is 100X larger than the other three maps in Figure 4(f-h)). Figure 4(i) presents the line profiles of z-height values across the scan areas in the diagonal direction. In the surface profiles, the S1 and S2 specimens exhibit the fluctuation of z-height in the levels of $\sim 20 \mu\text{m}$ and $\sim 0.4 \mu\text{m}$, respectively, while the polished specimens show

281 fluctuations of less than 0.1 μm . The surface profile of the S1 and S2 specimens tends to have
 282 more protruded peaks (local maxima) and valleys (local minima), while the polished
 283 specimens have relatively wide plateaus with dispersed valleys. It also corresponds to the
 284 probability distributions of z -height in S3 and S4 specimens, Figure 4(j), that have maximum
 285 probability points shifted to $+z$ direction from the origin.

286 These characteristics of surface roughness and z -height distribution could be
 287 quantified in several parameters, such as arithmetic mean roughness (R_a), root mean square
 288 roughness (R_q), skewness (Sk) and kurtosis (K) [40]. R_a is the arithmetic average of the
 289 absolute vertical deviation from the average height (m) and R_q is the standard deviation of
 290 vertical distance from the average height, both of which are widely used as standards to
 291 evaluate surface roughness.

$$292 \quad R_a = \frac{1}{L_x L_y} \int_0^{L_y} \int_0^{L_x} |z(x, y) - m| dx dy \quad (2)$$

$$293 \quad R_q = \sqrt{\frac{1}{L_x L_y} \int_0^{L_y} \int_0^{L_x} [z(x, y) - m]^2 dx dy} \quad (3)$$

$$294 \quad m = \frac{1}{L_x L_y} \int_0^{L_y} \int_0^{L_x} z(x, y) dx dy \quad (4)$$

295 Sk and K are the third and fourth moments of amplitude probability function, respectively,
 296 which represent an asymmetric spread of probability distribution far from a symmetric
 297 Gaussian function as well as the distribution of peaks and valleys in a profile.

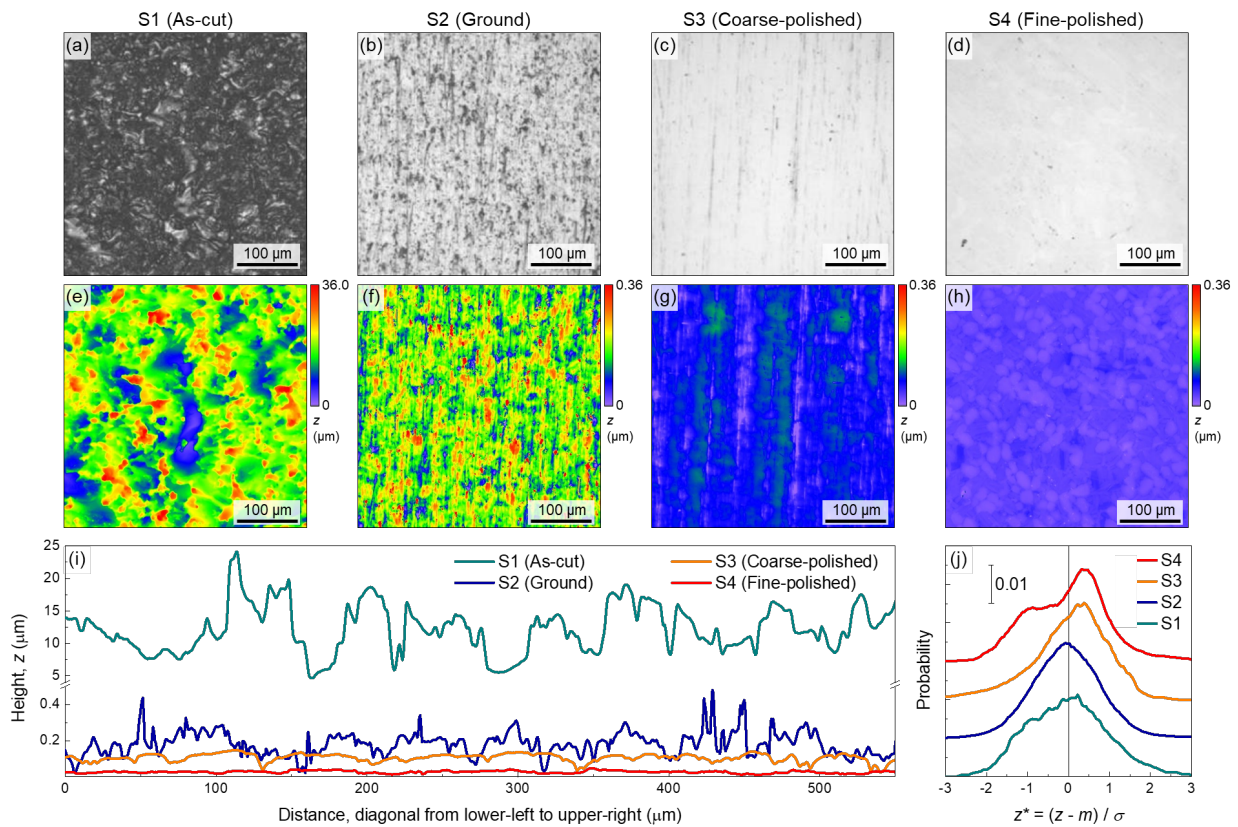
$$298 \quad Sk = \frac{1}{L_x L_y \sigma^3} \int_0^{L_y} \int_0^{L_x} [z(x, y) - m]^3 dx dy \quad (5)$$

$$299 \quad K = \frac{1}{L_x L_y \sigma^4} \int_0^{L_y} \int_0^{L_x} [z(x, y) - m]^4 dx dy \quad (6)$$

300 The values of average roughness and height descriptors (Sk and K) obtained from each
 301 topography map are listed in Table 3. The calculated surface roughness values correspond
 302 well to the qualitative insights from the surface line profiles. The variation of Sk and K values
 303 with surface finish will be discussed later in detail in the Discussion section.

304 During H-charging, each specimen was subjected to a constant charging current,

305 fixing the nominal current density. However, the true current density depends on the true
 306 geometrical area, which was estimated using the Zygo Mx post-processing software. The
 307 surface area of the four specimens compared to that of an ideally flat surface are also shown
 308 in Table 3. The S1 specimen has a significantly larger surface area, over 30 % than the ideally
 309 flat surface. The surface areas of the other three specimens are negligibly different, indicating
 310 that the current densities would be nearly the same, so the HE susceptibility can be compared
 311 directly. Caution should therefore be extended when comparing HE susceptibility of the S1
 312 specimen, since the true current density is approximately $\sim 30\%$ lower.



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 314 **Figure 4.** Optical microscopy images (a-d) and surface roughness maps (e-h) of the four specimen surfaces, (a,e)
 315 S1, As-cut, (b,f) S2, Ground, (c,g) S3, Coarse-polished, and (d,h) S4, Fine-polished. (i) Line profile of z-height
 316 values across the scan surfaces in the diagonal direction from lower-left to upper-right in (e-h). (j) Probability
 317 density distributions of z-height for the four specimens.

318 **Table 3.** Surface area, averaged surface roughness parameters and height distribution descriptor values
 319 obtained from the surface roughness maps in Figure 4.

Specimen	S1	S2	S3	S4
R_a (μm)	3.084×10^0	4.466×10^{-2}	1.471×10^{-2}	5.083×10^{-3}

R_q (μm)	1.829×10^1	6.240×10^{-2}	1.941×10^{-2}	6.503×10^{-3}
Sk	0.314	1.225	-0.958	-0.434
K	3.118	11.640	5.168	19.283
Surface area (% nominal)	131	100.31	100.0024	100.00051

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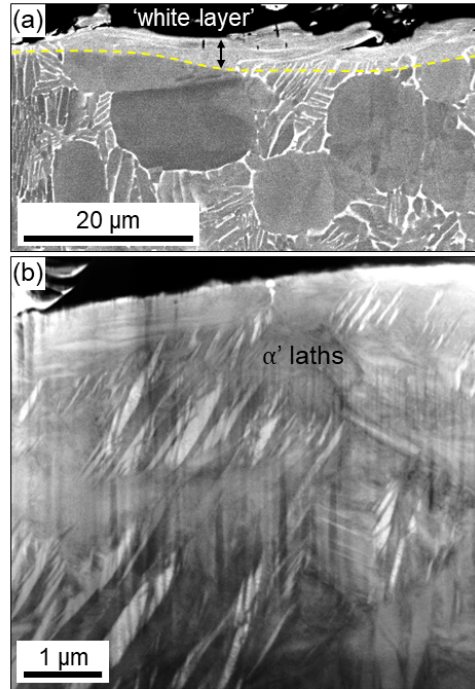
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Influences of surface finish on subsurface microstructures were investigated by electron microscopy imaging of cross-sections. The cut surface of S1 specimen retains perturbations induced by the rapid heating-cooling process during spark erosion of WEDM, as shown in Figure 5. A distinct and continuous surface layer, approximately $5\mu\text{m}$ in thickness, exists at the surface directly cut with WEDM. Such surface layers have been identified before, mostly in steels [41,42], formed due to the re-solidification of molten surface material during EDM. This re-cast layer has been termed the ‘white layer’ due to its appearance in the microscope [41,42]. Figure 5(b) shows the detailed microstructure of this layer, revealing fine, acicular laths which are 100-500 nm in thickness, which is typical of the α' (hcp) martensite. For this phase transformation to occur, the near-surface region would need to be cooled rapidly from above the β -transus at a rate exceeding the critical cooling rate for martensitic transformation ($> 410 \text{ K s}^{-1}$) [43]. It is expected that WEDM fulfills this requirement, as the rapid heating and cooling cycles lead to repeated quenching of the subsurface region. The cooling rate Ti-6Al-4V experiences during water quenching is $\sim 650 \text{ K s}^{-1}$ [44], so this could lead to a martensitic transformation. Two martensite phases can be formed in Ti alloys (α' and α''), which can be distinguished by their crystal structure, since α' is hcp and α'' is orthorhombic [1]. As the EBSD phase map in Figure S3 (in Supplementary Materials) indicates, this phase was matched to hcp α (no EBSD phase file was available for α'), allowing the phase to be characterized as α' rather than α'' , which agrees with the analysis from Stráský et al. [8]. Moreover, it is typically unexpected to form α'' in Ti-6Al-4V due to the usual requirement of a higher β stabilizer content; ($> 9.4 \text{ wt.}\%$ for vanadium) [1]. The transformation from β to α' is displacive, so occurs through a shear-type transformation in which the cooperative movement of atoms allows for a phase transformation without diffusion [1,3]. This transformation is facilitated by significant plastic deformation, resulting in the generation of interface dislocations and deformation twins [1,3,45]. Therefore, it is

346 reasonably expected that the S1 specimen contains a high dislocation density in the
347 subsurface area.



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349 **Figure 5.** (a) BSE image of cross-section near the charging surface in the S1 specimen before H-charging. (b)
350 STEM dark-field image of the martensite laths in the 'white layer'.

351 Although grinding effectively removes the EDM white layer, it plastically deforms the
352 surface at a finer scale, as highlighted in the surface topography examination. **Figure 6 shows**
353 **SEM electron channeling contrast (ECC) images and STEM micrographs of the S2 specimen**
354 **(a,b) and S4 specimen (c,d) before H-charging, respectively. The subsurface of the ground S2**
355 **specimen is still highly deformed compared to that of the polished S4 specimen, and exhibits**
356 **a large number of dislocation tangles in a depth of a few microns from the surface. This**
357 **clearly shows that the surface deformation during mechanical grinding is accommodated by**
358 **the generation of strain-induced dislocations, and further polishing procedures effectively**
359 **removes the deformed layer. It is important to note that the dislocation density has not been**
360 **quantified, and effects such as the dependence of α orientation on the active slip systems and**
361 **resulting dislocation response have not been considered here. However, considering the**
362 **considerable differences observed, it is clear that the non-polished specimens (S1 and S2)**
363 **are highly deformed, and this deformation level is significantly reduced during polishing.**

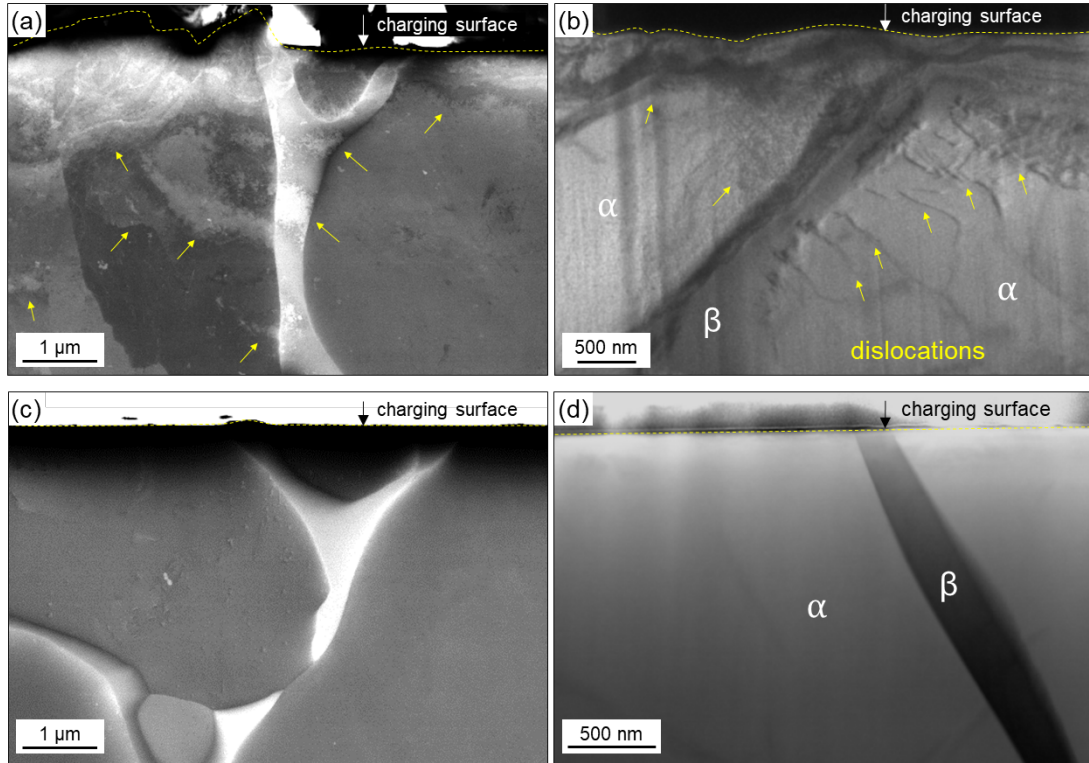


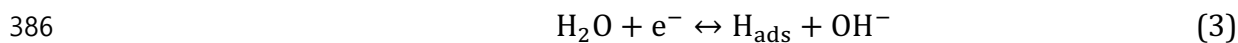
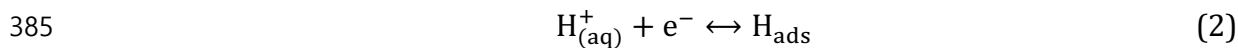
Figure 6. SEM ECC images (a,c) and STEM bright-field images (b,d) of cross-section near the charging surface. (a,b) S2 specimen. (c,d) S4 specimen. The yellow arrows in (a,b) highlight dislocation tangles and long dislocations in the subsurface.

3.3. Hydrogen entry and subsurface diffusion

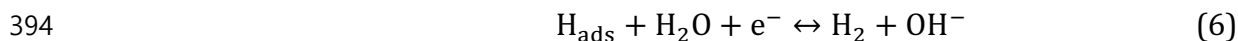
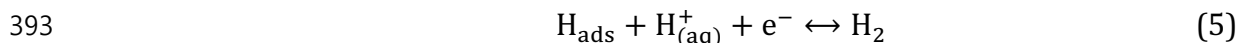
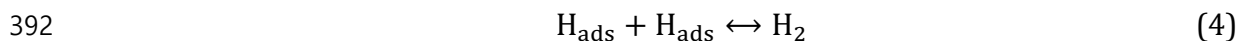
The assessments of microstructure and tensile deformation behavior have shown a clear difference in HE susceptibility between polished (S3 and S4) and non-polished (S1 and S2) specimens. The extensive hydride formation and resulting brittleness observed in the polished specimens suggest that H is readily able to enter the specimens and diffuse to nucleation sites for hydride formation (e.g. α/β boundaries). The non-polished specimens, however, seem to be protected under the employed charging conditions, showing no signs of HE. We used a direct observation of recombined hydrogen bubbles, TDS and SIMS to compare the amount of H-ingress and near-surface H-distribution. For these analyses, two representative specimens that show a significant difference in HE susceptibility were chosen for comparison; S2 (EDM and ground) and S4 (fine polished).

For H-charging in aqueous environment, all H products originate as protons (H^+) in

381 the electrolyte. Reduction of protons at the reaction surface forms adsorbed hydrogen
382 atoms (H_{ads}), which can be bonded to the surface either weakly by physisorption or strongly
383 by chemisorption [13]. The electrochemical reduction process is described by Equation (2)
384 and (3).



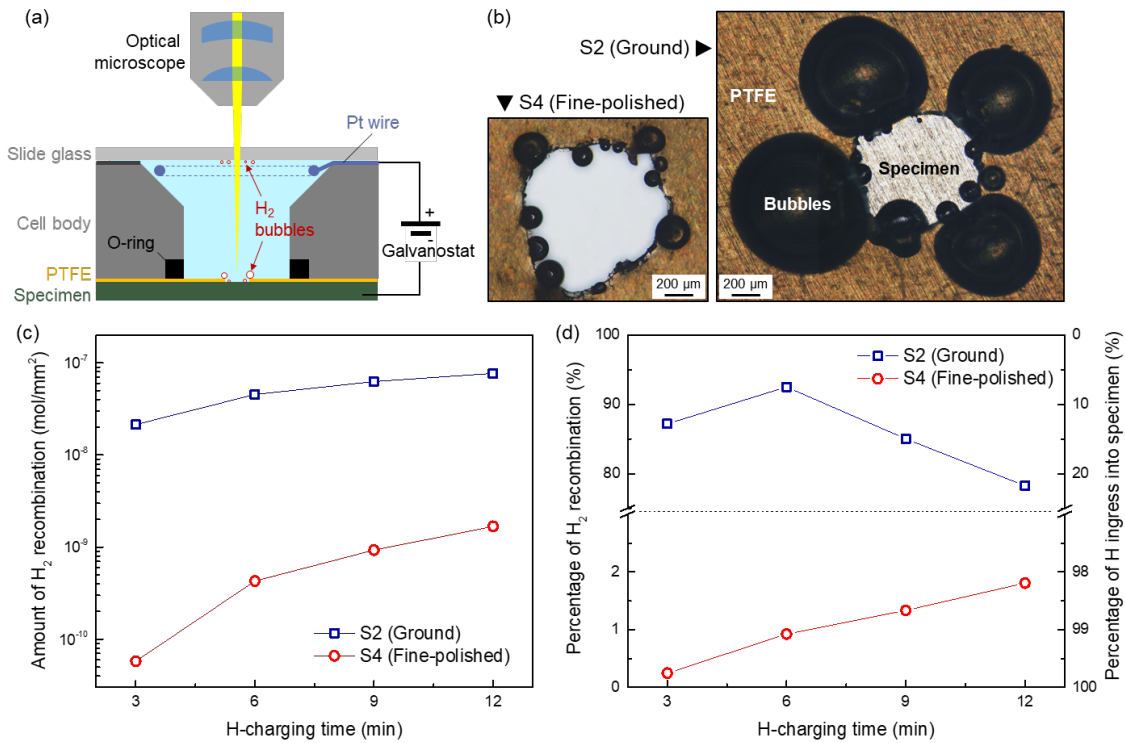
387 The adsorbed H then has three possible routes: (i) it may remain adsorbed on the
388 surface, (ii) it may be absorbed into the metal and cause HE, or (iii) it may recombine to form
389 molecular hydrogen (H_2) which would either dissolve in the aqueous solution or form gas
390 bubbles if the electrolyte solubility limit is exceeded [13]. The recombination reaction can
391 happen via the reactions described by Equation (4)-(6).



395 Since the adsorbed H can only exist at surface sites (only as a monolayer), its
396 concentration is negligible in comparison to the concentration of adsorbed H and
397 recombined H_2 . We measured the amount of recombined H_2 using the optical microscope
398 combined with an electrochemical cell (Figure 7(a), See the Experimental Methodology
399 section for the details of the setup). A small specimen area exposed to the electrolyte in the
400 cell was directly observed through the slide glass cover and the electrolyte during
401 electrochemical H-charging, as shown in the OM images in Figure 7(b). **The recombined H_2**
402 **bubbles were mostly trapped on the PTFE layer around its interface with the specimen, due**
403 **to the distinct wettability between them¹.** The amount of recombined H_2 molecules were

¹ The hydrophobic nature of PTFE (wetting angle $\theta = 118 - 165^\circ$, depending on the degree of elongation [54]) makes gas bubbles stay on the PTFE layer (to decrease the interface area between the PTFE and the aqueous electrolyte), while the hydrophilic Ti-6Al-4V surface ($\theta = 35^\circ$ [55]) helps H_2 molecules formed on the sample easily migrate toward the PTFE. So the H_2 gas bubbles accumulate at the PTFE/sample interface, but it does not mean that the H recombination to H_2 happens only at the interface.

404 estimated from the image analysis and the ideal gas law. The two-dimensional area (A_i) of the
405 bubbles in the images were analyzed using ImageJ software [46], and the volume of a bubble
406 (V_b) were estimated from the equivalent radius (r_{eq}) [47], which is the diameter of the circle
407 has the same area of the measured 2-D area of a single bubble ($A_i = \pi r_{eq}^2$, and $V_b = 4/3 \pi r_{eq}^3$).
408 The total amount of H₂ recombination per area by H-charging time is plotted in Figure 7(c).
409 The rough surface of S2 specimen recombines a significantly larger amount of
410 electrochemically reduced H to H₂ molecules than the polished surface of S4 specimen. One
411 electron in the applied electric current reduces a proton to an atomic H, so the total amount
412 of H reduction and the percentage of H₂ recombination (or the percentage of H ingress in to
413 the specimen, inversely) can be calculated from the measured data, as plotted in Figure 7(d).
414 Only around 10-20% of atomic H among the total amount of reduced H diffuses into the S2
415 specimen and the rest is recombined into H₂ bubbles. In contrast, the S4 specimen absorbs
416 most of reduced H and less than 2 % of H turns into H₂ bubbles. One should note that the
417 range of H-charging time is very short compared to that applied to the tensile specimens and
418 the electrochemical reaction in this initial stage is not in steady state. Indeed, the percentage
419 of H ingress increases with H-charging time for the S2 specimen while it decreases for the S4
420 specimen. The gas volume estimation using the equivalent radius and the ideal gas law could
421 induce a certain level of error in these measurements. The H absorption rate at the surface
422 would also be influenced by the H content at the subsurface region. It is clear that,
423 nevertheless, the rough surface recombines more H to H₂ molecules and absorbs less atomic
424 H into the material, than the polished surface.



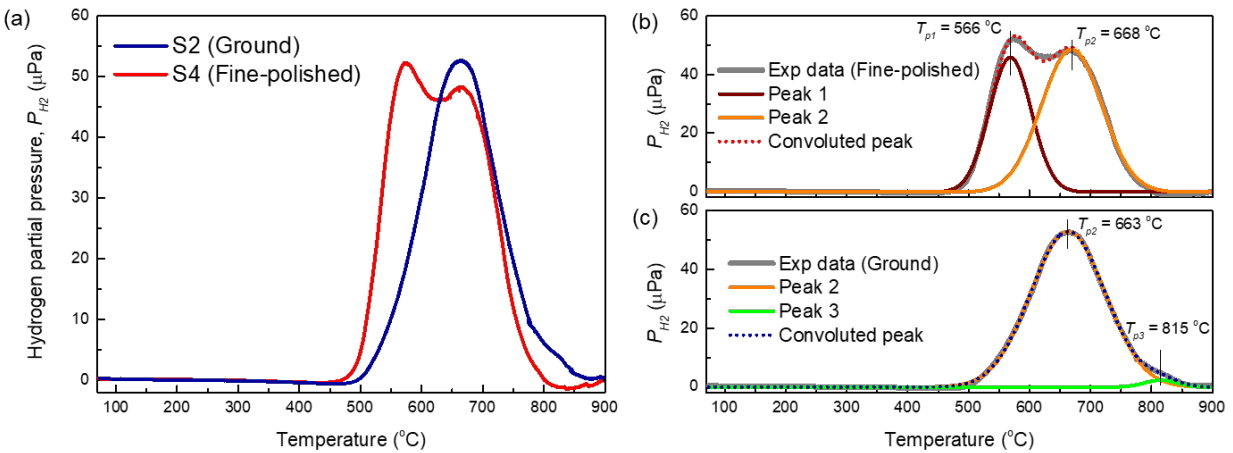
425

426 **Figure 7.** (a) Schematic diagram of the electrochemical cell combined with OM used for the direct analysis of
 427 H₂ bubbles. (b) OM images of H₂ bubbles around the H-charging area. Left: S4 specimen; Right: S2 specimen. (c)
 428 Amount of recombined H₂ molecules per area by H-charging time on the two specimens. (d) Percentages of H₂
 429 recombination (left y-axis) and H ingress into specimen (right y-axis) in the total amount of electrochemical H
 430 reduction.

431

432 We also measured the amount of H absorbed in the S2 and S4 specimens by TDS
 433 after 40 h H-charging. Figure 8(a) shows the hydrogen partial pressure spectrum of the two
 434 specimens. The atomic fraction of H measured from the curves was 1258 ppm and 1519 ppm
 435 for S2 and S4 specimens, respectively, which reveals that the polished specimen absorbed
 436 ~20 % more H than the ground specimen. Figure 8(b,c) presents the deconvoluted
 437 desorption peaks of each curve. The S4 specimen clearly exhibits two major peaks, of which
 438 maxima are located at 566 °C (Peak 1) and 668 °C (Peak 2), respectively. The curve of S2
 439 specimen has one major peak at 663 °C and a small peak (Peak 3) at 815 °C at the right
 440 shoulder of the major peak. Given the similarity of peak position and shape, the major peak
 441 can be considered to be the same with Peak 2 in Figure 8(b). H in this bimodal Ti-6Al-4V alloy
 442 diffuses through the β phase first, and starts to form the hydride phase in the α phase from
 443 the α/β interface when the β phase is saturated with H at a certain level [10,39]. This
 indicates that the Peak 2 that appears in the both curves originates from H stored in the β

444 phase. Given that the hydride phase were observed in the H-charged S4 specimen (Figure
 445 2(h) and Figure 3) but not in the S2 specimen, H signal related to Peak 1 comes from the
 446 decomposition of the hydride. The small amount of H related to Peak 3 that is observed only
 447 in the rough specimen is expected to originate from H trapped in the high-density defects in
 448 the subsurface region (Figure 6(a)), which will be further discussed with the SIMS results
 449 later. The TDS results suggests that the S2 specimen with the rough surface absorbs less H
 450 and H stored in the β phase does not induce a significant embrittlement in this alloy.

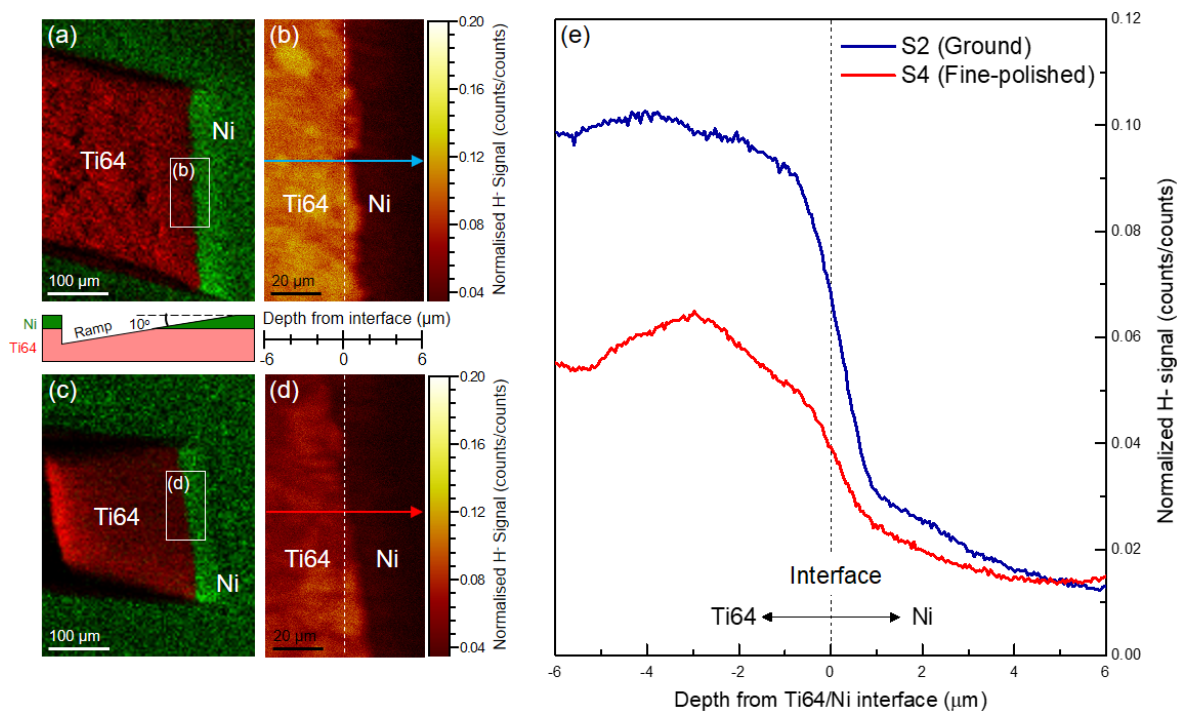


451
 452 **Figure 8.** (a) H_2 partial pressure-temperature curves of H-charged S2 and S4 specimens, measured by TDS. (b-
 453 c) Deconvolution of each curve to individual Gaussian peaks - (b) S4 specimen, (c) S2 specimen.

454 In addition to the surface roughness effect, the differences in subsurface
 455 deformation observed earlier would influence H diffusion flux in the subsurface, given that
 456 H is readily trapped at defects [14,48]. In order to compare the H content in the subsurface
 457 region SIMS was performed on the S2 and S4 specimens after H-charging. Ramp specimens
 458 inclined at 10° to the charging surface (Figure 9(a) and (c)) were ion-milled so that the H
 459 content could be compared with depth into the specimen. In order to protect the charging
 460 surface, a Ni layer was electrodeposited on the surface before ion-milling. The H^{-} ion maps in
 461 Figure 9(b) and (d) were taken in the local regions near the charging surface which are
 462 marked with rectangles in Figure 9(a) and (c). The H^{-} signal in the ion maps were normalized
 463 by the total ion signal to remove surface effects. The brighter contrast in the left part of Figure
 464 9(b) than that of Figure 9(d) indicates higher H concentration in the subsurface region under
 465 the ground surface compared to under the fine-polished surface. Line profiles along the

466 horizontal directions in the H⁻ ion signal maps show the difference more clearly, which are
467 plotted in Figure 9(d). The H content increases quite considerably in the Ti-6Al-4V specimens
468 in both cases compared to the protective Ni layer, suggesting that a considerable amount of
469 the H remains irreversibly trapped in the specimens after H-charging. The H content is nearly
470 twice as high for the S2 specimen compared to the S4 specimen, which reveals an interesting
471 difference considering the other two analyses previously suggested in this section. Despite
472 the recombined H₂ bubble analysis and TDS measurements suggesting that less H is
473 absorbed by the S2 specimen, it appears to have a considerably higher subsurface H
474 concentration than the S4 specimen, which corresponds to the Peak 3 observed in its TDS
475 result. (Figure 8(c)). The thicknesses of the H-accumulated layer and the deformed layer in
476 the subsurface region in the S2 specimen are not directly compared here, because (i) the
477 measured depth in the SIMS experiment was limited and (ii) the degree of subsurface
478 deformation is not uniform, as shown in the grains in Figure 6(a). However, given that the
479 only difference in the subsurface microstructure between the S2 and S4 specimens is the
480 degree of deformation (or defect density), it is reasonable to suppose that the high defect
481 density in the subsurface region causes the high H concentration detected in the SIMS
482 measurement². It is worth noting that hydrogen absorbed into the Ti-6Al-4V alloy first
483 diffuses through the β phase and forms a solid solution with the β phase by occupying
484 tetrahedral interstitial sites [10,39]. Even in the subsurface region with high-density
485 dislocations, the β phase would be still the primary accumulation site for hydrogen as shown
486 by TDS Peak 2 in Figure 8(c), but the high-density dislocations provide additional trapping
487 sites for hydrogen, as suggested by Peak 3 in Figure 8(c).

² Despite H-accumulation in the deformed subsurface region, no evidence of brittle cracking was observed in the subsurface region of the S2 specimen (See Figure S16 in Supplementary Materials). This might originate from either the high HE resistance of beta phase (because the majority of hydrogen exists in the beta phase) or the effect of high-density dislocations that distribute H more uniformly over the microstructure, which requires further investigation.



488

489 **Figure 9.** SIMS ion maps for (a,b) S2 specimen and (c,d) S4 specimen. (a) and (c) shows overlay of ion maps for
 490 Ti (TiO⁻ signal, red) and Ni (NiO⁻ signal, green). (b) and (d) show ion maps of normalized H⁻ signal. The schematic
 491 diagram between a and c describes the ramp morphology, and the scale bar between (b) and (d) shows depth
 492 from the Ni/Ti-6Al-4V interface in the ramp along the horizontal position in the H⁻ signal maps. (e) Line profiles
 493 of normalized H⁻ signal along the horizontal arrow lines in (b) and (d).

494

495 4. Discussion

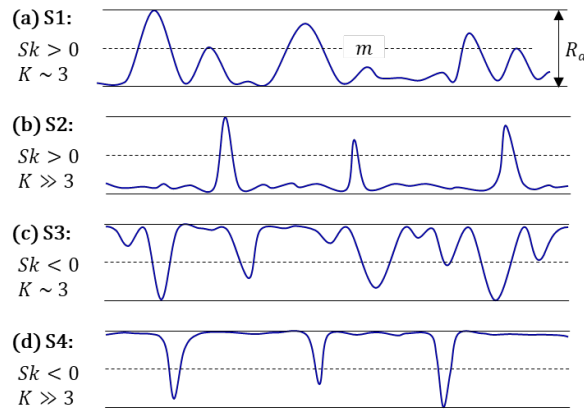
496 The experimental results clearly present that the roughened surfaces in both the S1
 497 and S2 specimens hinder H-absorption into them and assists in maintaining their ductility
 498 even after a harsh electrochemical exposure to hydrogen. In contrast, specimens S3 and S4
 499 with polished surfaces exhibit extensive hydride formation and consequent embrittlement,
 500 as previously reported [10]. We investigated the influence of surface state on H-absorption
 501 processes by separating the possible factors into two; electrochemical activity change by
 502 surface roughness and enhanced H-trapping by subsurface deformation. The possibility of
 503 formation of a thicker oxide layer that can act as a H-permeation barrier on the S1 and S2
 504 surfaces was ruled out by STEM-EDS analyses (See Supplementary Materials). Other factors
 505 such as local composition or crystallographic orientation that are known to influence the
 506 electrochemical properties of catalysts [49,50] are not considered here, because H-charging

507 in this study was performed on millimeter-scale areas of the Ti-6Al-4V alloy without a strong
508 crystallographic texture; in the present case all the specimens will have had identical textures
509 in any case.

510 Considering the previous observations on the effects of deformation on corrosion
511 behavior of different metals [19–21], surface roughness should alter electrochemical activity.
512 From a simple fact that a rougher surface has a larger surface area (Table 3), one could expect
513 a higher H-flux through the surface. However, the H₂ bubble analysis in Figure 7 clearly
514 demonstrates that the rough surface induces a higher fraction of recombination to H₂ gas
515 (Equations 4-6) – in other words, a smaller fraction of atomic hydrogen is absorbed into the
516 surface. Under constant current control (employed for all H-charging processes in this study),
517 the rate of total H⁺ reduction at the cathode is same for all specimens but the higher activity
518 at the rough surface promotes only the recombination reactions, which reduces the amount
519 of H absorption that causes embrittlement.

520 It is intriguing that the HE behavior in these specimens shows such a pronounced
521 change between the two groups; non-polished specimens (S1 and S2) and polished
522 specimens (S3 and S4). The estimated surface area values in Table 3 (~ 30% larger, and only
523 in sample S1) suggests that roughening-induced increase of surface area would not be a
524 critical factor in the hydrogen uptake in this alloy. Similarly, the difference in average
525 roughness, either R_a or R_q , between specimens S1 and S2 is a few orders of magnitude larger
526 than that between the S2 and S3 specimens. This also implies that the average roughness (or
527 height difference between peaks and valleys) does not play a decisive role in the
528 improvement of HE resistance. The average roughness values do not provide any information
529 about shape and distribution of asperities (i.e. peaks and valleys) that are influential to local
530 electron flux [16]. As mentioned in Section 3.2, skewness (Sk) and kurtosis (K) describes an
531 asymmetry of probability distribution and represent distribution of peaks and valleys in a
532 surface roughness profile [40]. The surface profiles of the four specimens investigated in this
533 study can be categorized with the Sk and K values, as described schematically in Figure 10. A
534 negative Sk value indicates a shift of probability distribution to +z direction from the origin.
535 This means a larger number of height values above the average height, which represents a
536 topography with relatively wide plateaus above the average height. The remaining minor

537 number of height values below the average represents surface valleys. In other words, a
 538 negative Sk indicates a surface dominated by valleys over peaks. For a positive Sk value, the
 539 wide plateaus are above the mean height and peaks dominate over valleys. K is a measure of
 540 peak and valley sharpness within the surface roughness profile. A symmetric Gaussian
 541 distribution has $K = 3$. A large K value above 3 indicates a pointed probability distribution,
 542 and sharper peaks and valleys in the surface profile. The clear division of Sk values into the
 543 two groups of non-polished samples (positive) and polished samples (negative) indicates
 544 that the existence of pronounced peaks plays a critical role in promoting the H-
 545 recombination reaction and reducing the amount of H-uptake. In other words, a few
 546 scratches on a flattened surface as the case of S3 specimen are not able to efficiently reduce
 547 H-uptake even though they increase the average roughness. The decreased electron work
 548 function at peaks [16] could promote a higher density of hydrogen reduction compared to a
 549 flat surface, and the excess amount of adsorbed hydrogen (H_{ads}) at the peaks recombines
 550 easily into H_2 molecules. The influence of peak (or valley) sharpness represented by K was
 551 not clear in the HE behavior in the tested condition of this study. Given that sharper peaks
 552 have a smaller work function [16], the peak sharpness might also influence the H-uptake
 553 behavior of rough surfaces (especially in long-term H-ingress), which requires further study.



554
 555 **Figure 10.** Schematic illustration for surface roughness profiles with different skewness (Sk) and kurtosis (K),
 556 in the cases of specimens S1 to S4. R_a and m is the arithmetic mean roughness and mean height, respectively.

557 Grinding generates a high density of dislocations by plastically deforming the surface,
 558 and subsequent polishing processes using diamond or silica suspensions effectively remove
 559 the deformed subsurface layer, as shown in Figure 6. The EDM white layer with α' martensite

560 in the S1 specimen in Figure 5a also contains a high density of lath boundaries as well as
561 geometrically necessary dislocations for accommodating a small angular deviation in
562 crystallographic orientation between the laths (or between the laths and matrix). Grain
563 boundaries, lath boundaries and dislocations are effective H-trapping sites, serving as sinks
564 which accumulate H and reduce the effective diffusion coefficient [14,48,51]. The high
565 density of H-trapping sites in the subsurface region hinders not only H-diffusion into the
566 material interior but also H-absorption at the surface. The net flux of hydrogen atoms
567 absorbed into the metal can be described by Equation 8 [12],

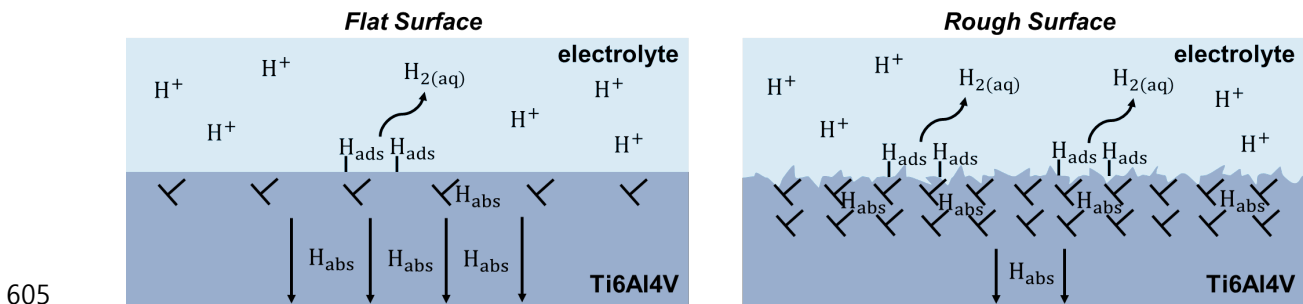
568
$$J(\text{H}_{\text{abs}}) = k_{\text{abs}}A_T\theta_{\text{ad}} - k_{\text{des}}C_0(1 - \theta_{\text{ad}}) \quad (8)$$

569 where θ_{ad} is the surface coverage of adsorbed hydrogen atoms, k_{abs} and k_{des} are the
570 absorption and desorption rate constants respectively, A_T is an Arrhenius term dependent on
571 hydrostatic stress, and C_0 is the sub-surface lattice hydrogen concentration. A greater trap
572 density underneath the roughened surfaces would result in a higher C_0 , as shown by the SIMS
573 results in Figure 9, reducing the H-absorption flux. A higher recombination ratio on the
574 surface would decrease the amount of surface-adsorbed hydrogen (θ_{ad}), further reducing
575 the net H-uptake flux.

576 Considering the results of comprehensive analyses of H recombination and uptake in
577 Section 3.3, the enhanced HE-resistance of roughened specimens against electrochemical H-
578 charging can be summarized as shown in Figure 11. Polishing reduces the electrochemical
579 activity of the surface, which decreases the recombination ratio and means more H is
580 available for entry into the material. The polishing treatment also reduces the subsurface
581 deformation and decreases the density of defects that act as H-trapping sites. On the other
582 hand, a rough surface (dominated by peaks) such as the as-cut or as-ground states promotes
583 the recombination reaction, reducing the amount of absorbable hydrogen at the surface. The
584 higher density of H-trapping sites from subsurface deformation decreases the
585 thermodynamic driving force for H entry due to a reduced H concentration gradient across
586 the electrolyte-metal interface, as well as a decrease in the effective H-diffusivity in the
587 deformed subsurface region. **H accumulation in the deformed subsurface would induce a
588 large concentration gradient of H that eventually drives H diffusion to the material interior;**

589 but the internal stress gradient between the subsurface and the interior can hinder H
590 diffusion further [52].

591 It is proposed that these effects combine to impede both H entry and transport when
592 the alloy surface is roughened, which leads to improved HE-resistance during the employed
593 electrochemical H-charging. It is worth noting that similar phenomena were reported for Ti-
594 6Al-4V specimens in a gaseous H environment at 650 °C [53] – a polished specimen forms
595 TiH_2 hydride while a rough ground one does not in the same condition, which was mainly
596 attributed to a higher oxygen concentration at the ground surface than the polished surface.
597 The influences of roughness and subsurface defects were not considered in the reference
598 [53]. However, H-uptake from gaseous hydrogen is a competition between H_2 dissociation
599 and recombination, so it might be possible that the rough surface also promotes H
600 recombination even in gaseous hydrogen environments. Regardless of the hydrogen source,
601 defects underneath the rough surface could trap H unless the temperature is high enough to
602 induce thermal atomic vibration that overcomes the trapping energy of the defects. Further
603 studies are needed for investigating clearly the effects of surface finish on H-uptake in a
604 gaseous hydrogen environment.



605
606 **Figure 11.** Representation of H behavior at polished flat surfaces and non-polished rough surfaces with surface
607 peaks. The rough surface is more active for recombination of H_{ads} into H_2 due to the surface peaks and less H
608 enters the material. The higher density of dislocations under the rough surface also increases the amount of
609 trapped H in the subsurface volume, which blocks H_{abs} diffusion further into the sample.

610

611 5. Conclusions

612 The susceptibility of Ti-6Al-4V to HE in electrochemical H-charging has been
613 investigated and compared among specimens with different surface finishes achievable

614 through standard preparation techniques. A major difference in HE susceptibility was
615 observed between polished and non-polished specimens: upon electrochemical H-charging,
616 polished specimens are significantly more susceptible to HE, while the non-polished ones
617 with roughened surfaces do not show a clear reduction in ductility compared to uncharged
618 material. The direct observation analysis of recombined H₂ bubbles and TDS analysis
619 revealed that the roughened surface with protruded surface peaks exhibits a higher
620 electrochemical activity than a polished flat surface, which increases the H recombination
621 ratio and reduces the H-ingress flux. This causes a significantly smaller amount of atomic H
622 to be absorbed by the rough surface at constant current, than by the polished surface. In
623 addition to the change in H-recombination ratio, surface roughening induces a higher density
624 of defects, or H-trapping sites, which decreases the effective H-diffusivity as well as hinders
625 H-ingress by decreasing the concentration gradient at the metal-electrolyte interface. These
626 combined effects resulting from the increased roughness of the surface provide the enhanced
627 resistance against HE in the aqueous electrochemical H-environment by impeding H-
628 transport to the material interior.

629 The implications of these findings are notable both for researchers conducting H-
630 charging experiments, and for industries concerned with aqueous HE in service. For the
631 former, this work has shown that the specimen surface conditions are crucial in experimental
632 design, and that even small changes to preparation processes can have significant effects on
633 H-uptake. Thus, when comparing HE after electrochemical charging, it is essential to ensure
634 minimal variation in surface preparation procedures among samples. In the case of the latter,
635 these results highlight new opportunities. Surface treatments such as etching, machining and
636 polishing are already widely used to address fatigue, wear and corrosion challenges. For
637 components exposed to aqueous hydrogen environments, HE susceptibility is an additional
638 concern that, based on our results, can be addressed by engineering the surface roughness.

639

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645

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823

824 **List of figure captions**

825 **Figure 1.** (a) BSE micrograph and (b) EBSD inverse pole figure map of Ti-6Al-4V alloy used
826 in this study. (c) Tensile stress-strain curves of the uncharged specimen and H-charged
827 specimens with four different surface states. The uncharged specimen was tested in the as-
828 cut state. The inset graph shows an enlarged plot of stress-strain curves near fracture point
829 of polished specimens. The inset images show the DIC maps of local Von Mises strain at the
830 moment before failure for the ground (S2) and fine-polished (S4) specimens.

831 **Figure 2.** Cross-section BSE images of the four specimens with different surface finishes,
832 after H-charging for 40 h. (a,b) S1, As-cut. (c,d) S2, Ground. (e,f) S3, Coarse-polished. (g,h) S4,
833 Fine-polished. The upper row are images near the charging surfaces and the lower row are
834 images near the center of the specimen.

835 **Figure 3.** (a) BSE image and (b) EBSD phase map of the fine-polished (S4) specimen after H-
836 charging for 40 h. Data points only with confidence index over 0.1 are shown here. Note that
837 the hydride phase observed in the Ti-6Al-4V alloy has a slightly distorted structure ($c/a \sim$
838 1.013) compared to the equilibrium fcc δ -hydride phase found in pure Ti, and the β -phase is
839 not well indexed (black) in the EBSD measurement due to non-uniform lattice expansion by
840 H [10,39].

841 **Figure 4.** Optical microscopy images (a-d) and surface roughness maps (e-h) of the four
842 specimen surfaces, (a,e) S1, As-cut, (b,f) S2, Ground, (c,g) S3, Coarse-polished, and (d,h) S4,
843 Fine-polished. (i) Line profile of z-height values across the scan surfaces in the diagonal
844 direction from lower-left to upper-right in (e-h). (j) Probability density distributions of z-
845 height for the four specimens.

846 **Figure 5.** (a) BSE image of cross-section near the charging surface in the S1 specimen before
847 H-charging. (b) STEM dark-field image of the martensite laths in the 'white layer'.

848 **Figure 6.** SEM ECC images (a,c) and STEM bright-field images (b,d) of cross-section near the
849 charging surface. (a,b) S2 specimen. (c,d) S4 specimen.

850 **Figure 7.** (a) Schematic diagram of the electrochemical cell combined with OM used for the

851 direct analysis of H₂ bubbles. (b) OM images of H₂ bubbles around the H-charging area. Left:
852 S4 specimen; Right: S2 specimen. (c) Amount of recombined H₂ molecules per area by H-
853 charging time on the two specimens. (d) Percentages of H₂ recombination (left y-axis) and H
854 ingress into specimen (right y-axis) in the total amount of electrochemical H reduction.

855 **Figure 8.** (a) H₂ partial pressure-temperature curves of H-charged S2 and S4 specimens,
856 measured by TDS. (b-c) Deconvolution of each curve to individual Gaussian peaks - (b) S4
857 specimen, (c) S2 specimen.

858 **Figure 9.** SIMS ion maps for (a,b) S2 specimen and (c,d) S4 specimen. (a) and (c) shows
859 overlay of ion maps for Ti (TiO⁻ signal, red) and Ni (NiO⁻ signal, green). (b) and (d) show ion
860 maps of normalized H⁻ signal. The schematic diagram between a and c describes the ramp
861 morphology, and the scale bar between (b) and (d) shows depth from the Ni/Ti-6Al-4V
862 interface in the ramp along the horizontal position in the H⁻ signal maps. (e) Line profiles of
863 normalized H⁻ signal along the horizontal arrow lines in (b) and (d).

864 **Figure 10.** Schematic illustration for surface roughness profiles with different skewness (Sk)
865 and kurtosis (K), in the cases of specimens S1 to S4. R_a and m is the arithmetic mean
866 roughness and mean height, respectively.

867 **Figure 11.** Representation of H behavior at polished flat surfaces and non-polished rough
868 surfaces with surface peaks. The rough surface is more active for recombination of Hads into
869 H₂ due to the surface peaks and less H enters the material. The higher density of dislocations
870 under the rough surface also increases the amount of trapped H in the subsurface volume,
871 which blocks Hads diffusion further into the sample.

872

873

874 **List of tables**

875

876 **Table 1.** Details of the methods used to prepare the H-charging surface of each specimen.
877 Whole preparation steps of each specimen include the preparation steps of the one above it.

878 **Table 2.** Average mechanical properties of specimens obtained from three repeats for each
879 case.

880 **Table 3.** Surface area, averaged surface roughness parameters and height distribution
881 descriptor values obtained from the surface roughness maps in Figure 4.

882

Supplementary Materials

A. Error propagation analysis of the tensile test results of small specimens

In the main text, we focus our attention mostly on the difference in the failure strain between the non-polished (S1 and S2) and polished (S3 and S4) specimens. There are, however, as can be seen in Fig. 1 and Table 1, several other differences among the measured property values. To assess the significance of the differences, an error propagation analysis was carried out. Based on the measurement uncertainty of a digital micrometer (used to measure gauge thickness) and the estimated uncertainty in the optical microscope measurements (used to measure gauge width), the percentage uncertainty in the measurement of gauge area was calculated to be $\sim 1\%$. This is four orders of magnitude higher than the percentage error in the force measurements from the micro-mechanical testing system, showing that the uncertainty in the stress is dominated by uncertainty in the area measurement. The respective uncertainties were combined through Equation (1) to generate a measured uncertainty (u_σ) in the proof stress and UTS measurements, where σ is the stress, A is the gauge area, and F is the force [34].

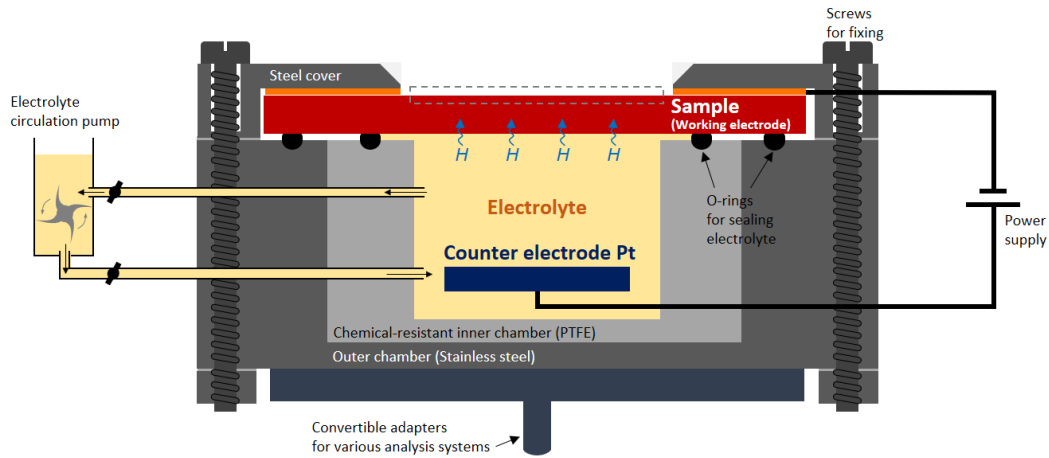
$$\left(\frac{u_\sigma}{\sigma}\right)^2 = \left(\frac{u_A}{A}\right)^2 + \left(\frac{u_F}{F}\right)^2 \quad (1)$$

From this analysis, the average error in both the proof stress and UTS values were calculated to be ~ 10 MPa. This error is not insignificant, but it is also not high enough to account entirely for the observed scatter generated from repeat measurements (as included in Table 2). The observed scatter ranges from 8-40 MPa in the proof stress and 7-27 MPa in the UTS based on three repeats. This discrepancy is likely a result of so-called ‘scale effects’, which influence variability when small test pieces are used [34]. Miniaturizing test coupons make experiments more susceptible to influence from factors such as residual stresses, misalignment and surface effects (particularly relevant here due to the different surface finishes used) [34]. This creates larger observed errors than those generated purely through measurement uncertainty, so it is these observed errors that the significance of the results will be measured against. In general, the variations in proof stress and UTS between

911 specimens fall within the range of the observed errors (based on repeats), so little attempt is
912 made to compare these values among specimens. An exception is the lower proof stress
913 exhibited by the polished specimens, which can be accepted as a feature of HE since the
914 magnitude by which they differ from the other specimens (~ 100 MPa) is significantly higher
915 than the observed scatter. Similarly, the differences in strain to failure between the S1, S2 and
916 uncharged specimens have not been directly compared, since their differences are
917 comparable to the observed scatter. However, the drastic decrease in fracture strain between
918 polished and non-polished specimens is certainly significant, since the change is several
919 times higher than the largest error reported. Therefore, we focus on the origin of the different
920 fracture strain in the H-charged specimens here – in other words, the different susceptibility
921 to hydrogen embrittlement by surface state.

922

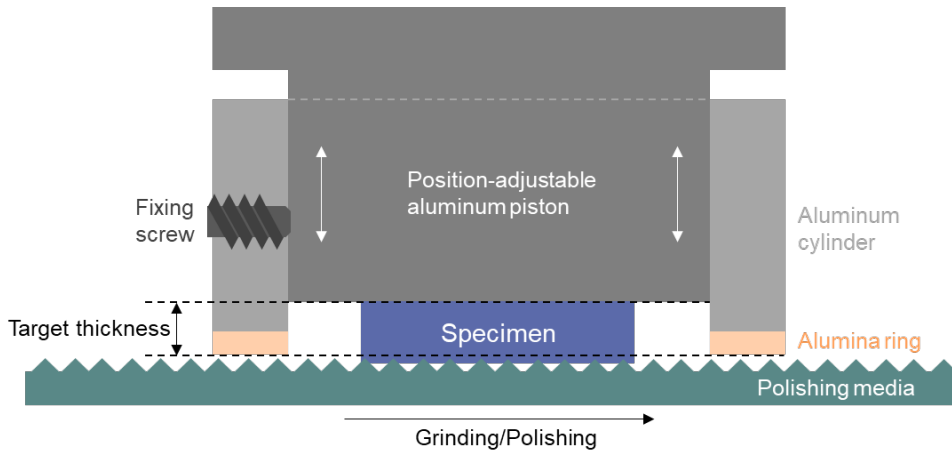
923 B. Supplementary Figures



924

925 **Figure S11.** Schematic diagram of the electrochemical cell used in this study for H-charging (reproduced
926 from [30]).

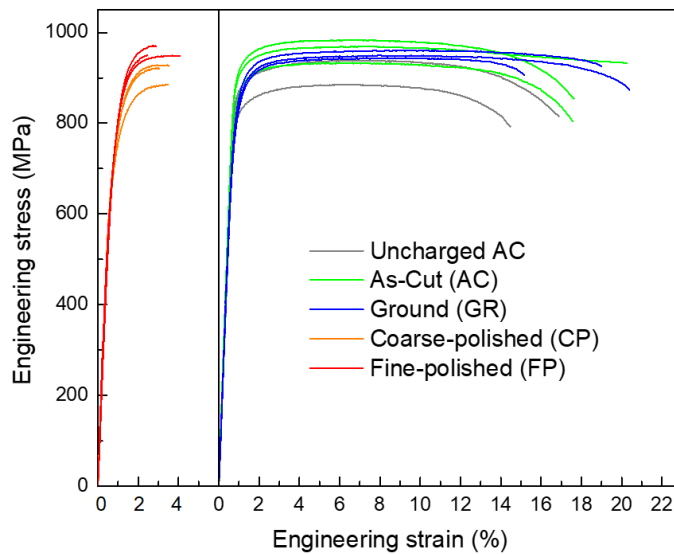
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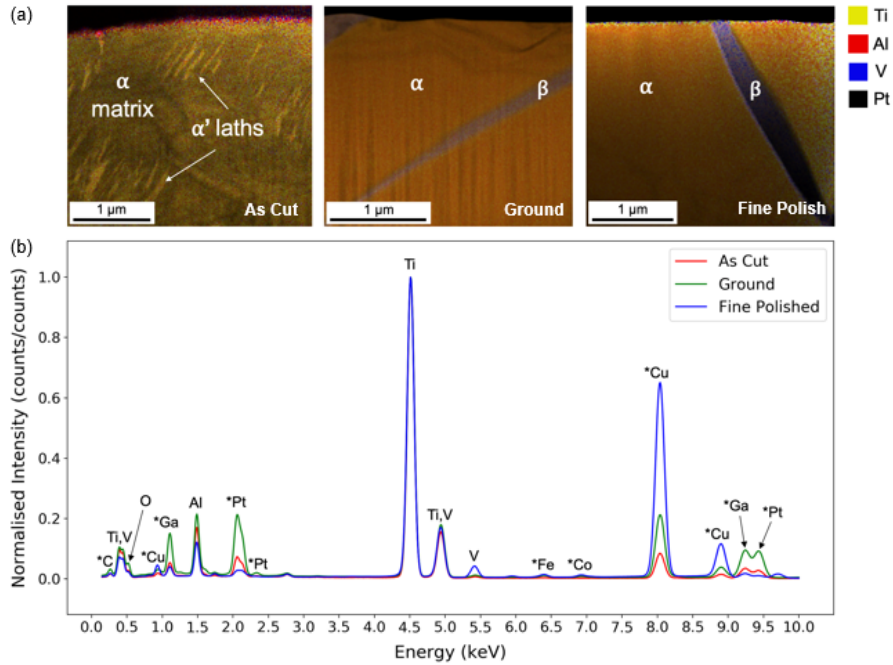
929 **Figure S12.** A thickness-controllable specimen mount used in specimen preparation in this study. The
 930 outer aluminum cylinder has an alumina ring with extremely low abrasion rate, which minimizes the
 931 thickness change of the outer body. A specimen can be glued on the position-adjustable piston, which
 932 enables to adjust the target thickness.

933



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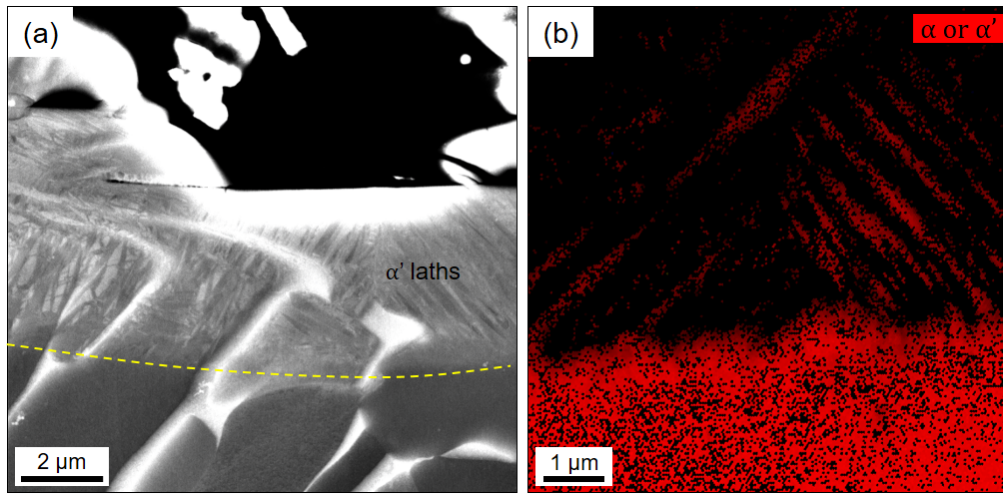
935 **Figure S13.** Engineering stress-strain curves from all repeated tensile tests of specimens with different
 936 surface finishes after H-charging and uncharged S1 specimens.



937

938 **Figure S14.** STEM-EDX results for As-Cut (S1), Ground (S2) and Fine Polish (S4) specimens. (a) Overlay
 939 maps showing the elemental distribution in the three specimens. (b) EDX spectra from the entire region
 940 in (a), with peaks labelled according to the elements that they represent. *Refers to elements not
 941 contained within the alloy; e.g. Cu from the EDM electrode wire and TEM sample holder.

942

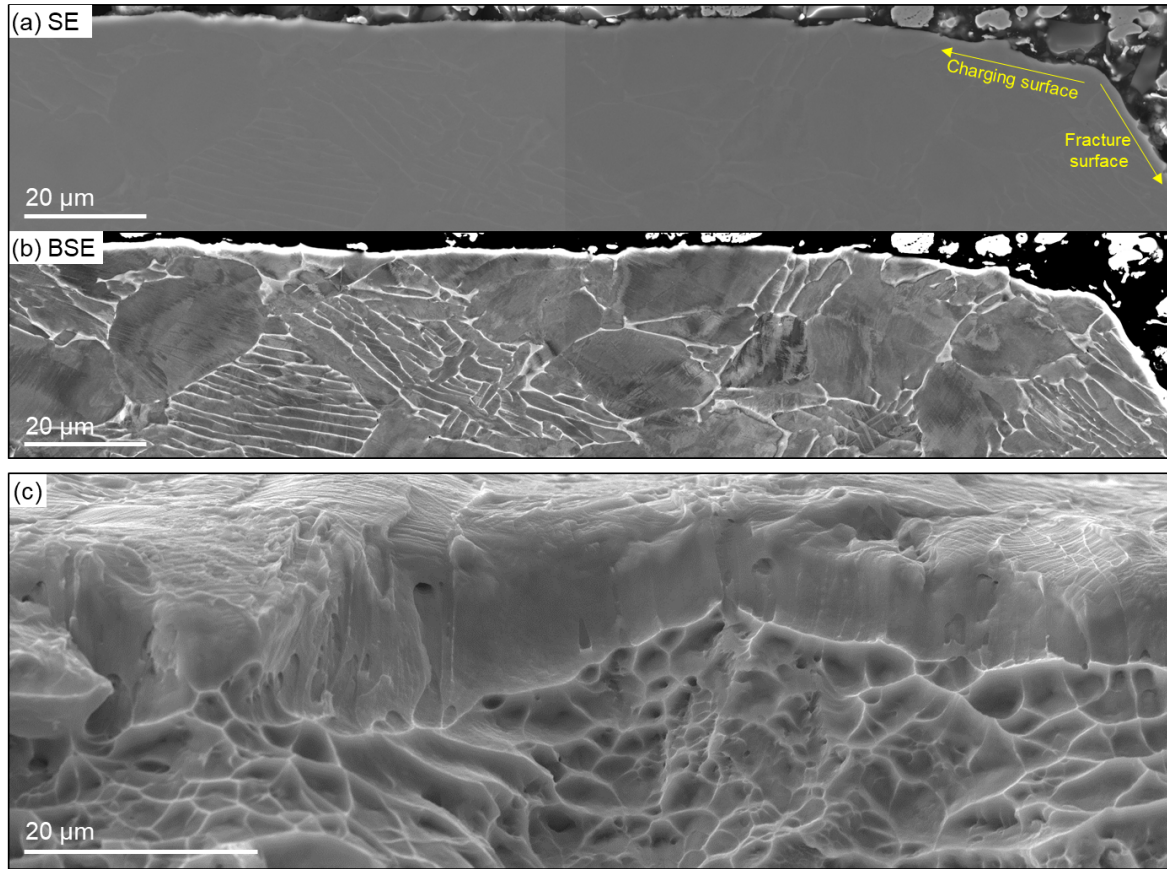


943

944 **Figure S15.** BSE micrograph of α' martensite region in the EDM white layer of the As-Cut (S1) specimen.
 945 (d) EBSD phase map of a region in the white layer, matching the laths to a hcp phase.

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Figure S16. (a,b) Cross-section SEM images of the H-charged S2 specimen after fracture; (a) SE and (b) BSE images. (c) SE image of the fracture surface of the H-charged S2 specimen near the charging surface.